

Solid State Power Amplifier Module 800 to 2500MHz, 250 Watts MODEL BME88258-250

Features:

- Highest Power Density to Footprint Ratio
- Ultra Wideband Operation
- Highest Efficiency Over the Entire Bandwidth
- Rugged and Reliable
- Extreme Temperature Range Usage
- RF Input/Output Sample Ports
- Internal DC to DC Converters
- Optional T/R Pin Switch Available
- Suitable Building Block for Rack Mounted Systems



Performance Specifications

Frequency Range:
RF Power Output (P3dB):
Saturated Power Output (Psat):
250 Watts Typical
280 Watts

RF Input Range:

RF input Overdrive:

-15 to -8dBm Typical

20 dBm Max.

• DC Bias: AB Linear

 Modulation Format: Multi-tone, CW, AM, FM, Pulse

Input VSWR:
 Output Load VSWR:
 Harmonic (In Band 2nd/3rd):
 2.0:1 Typical
 <-13 dBc Typical

• IM Products (4 Tones): <-12 dBc Typical

Spurious: <-60 dBc
 Stability: Open/Short Tested
 Built in Test: Composite Fault Indication

(Over Temperature, Over Voltage, Over Current) RF In/RF Out Sample Ports: Yes
Control Interface: RS-422
PA Enable/Disable: Low Vol

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 DC Input: 18-32Vdc

DC Power @ 28V: 1200W Typical
Efficiency (DC to RF): 25% Typical
Noise Power Output: -80dBm/Hz typical

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 RF Connectors: RF Input and Sample Ports: SMA (3X)

RF Output: TNC-Female

Interface Connector: D-Subminiature

Operating Temperature: -40 to 85°C Baseplate

(external heatsink required)

Environmental: Shock/Vibration MIL-STD-

810F Size: 15" x 9" x 2.25"

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 Weight: 16.2 lbs.

COMTECH PST proudly introduces the highest power solid state RF modules available in the marketplace today. Comtech's latest development expands on its proven innovative integrated RF GaN Power Amplifier designs by further increasing the RF power density, while improving overall operating efficiency. Consistent with its planned technology development roadmap, Comtech is leading the field with the latest in GaN-based RF device performance and advanced amplifier development. These highly integrated designs are ideal for use in communication, electronic warfare, and radar transmitter systems where space, cooling, and power are limited. Applications include ground (dismounted, mobile or fixed), surface, and airborne platforms.